MOSPEC

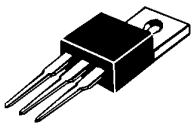
MBR30100CT

Schottky Barrier Rectifiers

Using the Schottky Barrier principle with a Refractory metal capable of high temperature operation metal. The proprietary barrier technology allows for reliable operation up to 175℃ junction temperature. Typical application are in switching Mode Power Supplies such as adaptors, DC/DC converters, free-wheeling and polarity protection diodes.

SCHOTTKY BARRIER RECTIFIERS

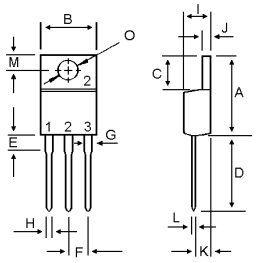
30 AMPERES
100 VOLTS



TO-220AB

Features

- ＊Low Forward Voltage.
- ＊Low Switching noise.
- ＊High Current Capacity
- ＊Guarantee Reverse Avalanche.
- ＊Guard-Ring for Stress Protection.
- ＊Low Power Loss & High efficiency.
- ＊175℃ Operating Junction Temperature
- ＊Low Stored Charge Majority Carrier Conduction.
- ＊Plastic Material used Carries Underwriters Laboratory
- ＊Flammability Classification 94V-O
- ＊*Pb free*
- ＊*In compliance with EU RoHs directives*



MAXIMUM RATINGS

Characteristic	Symbol	MBR30100CT	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V_{RRM} V_{RWM} V_R	100	V
RMS Reverse Voltage	$V_{R(RMS)}$	70	V
Average Rectifier Forward Current (per diode) Total Device (Rated V_R)	$I_{F(AV)}$	15 30	A
Non-Repetitive Peak Surge Current (Surge applied at rate load conditions halfware, single phase, 60Hz)	I_{FSM}	250	A
Operating Junction Temperature Range	T_J	+175	℃
Storage Temperature Range	T_{stg}	-65 to +150	℃

DIM	MILLIMETERS	
	MIN	MAX
A	14.68	16.00
B	9.78	10.42
C	5.02	6.60
D	13.00	14.62
E	3.10	4.19
F	2.41	2.67
G	1.10	1.67
H	0.69	1.01
I	3.21	4.98
J	1.14	1.40
K	2.20	3.30
L	0.28	0.61
M	2.48	3.00
O	3.50	4.00

THERMAL RESISTANCES

Typical Thermal Resistance junction to case	$R_{\theta jc}$	3.0	℃/w

ELECTRICAL CHARACTERISTICS

Characteristic	Symbol	MBR30100CT	Unit
Maximum Instantaneous Forward Voltage (per diode) (I_F =15 Amp T_C = 25℃) (I_F =15 Amp T_C = 125℃)	V_F	0.86 0.78	V
Maximum Instantaneous Reverse Current (Rated DC Voltage, T_C = 25℃) (Rated DC Voltage, T_C = 125℃)	I_R	0.01 15	mA
Typical Junction Capacitance (Reverse Voltage of 4 volts & f=1 MHz)	C_P	290	pF

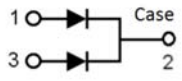


FIG-1 FORWARD CURRENT DERATING CURVE

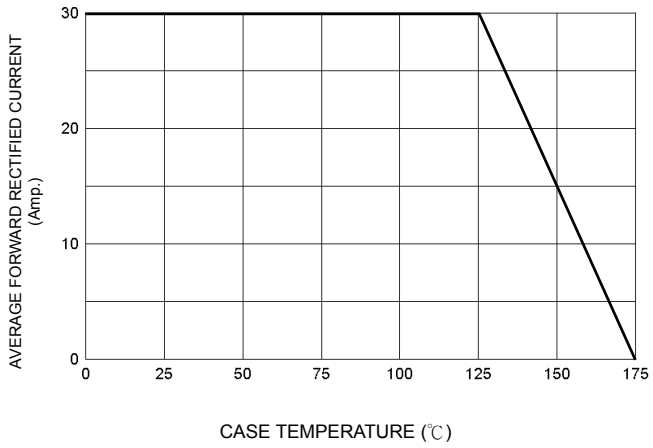


FIG-2 TYPICAL FORWARD CHARACTERISTICS

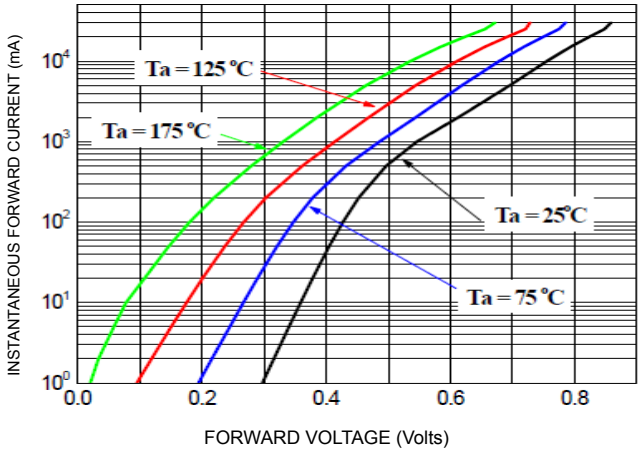


FIG-3 TYPICAL REVERSE CHARACTERISTICS

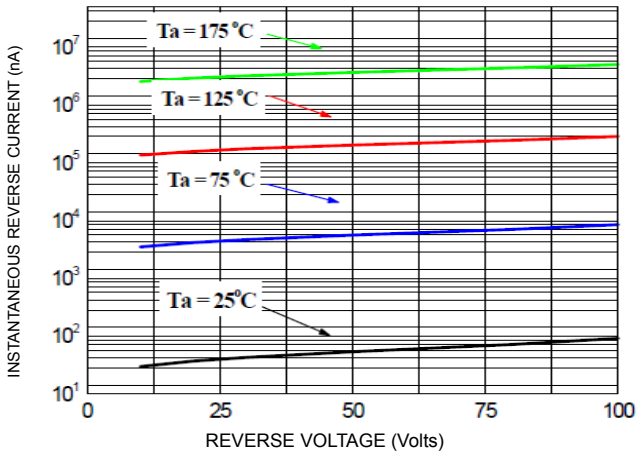


FIG-4 TYPICAL JUNCTION CAPACITANCE

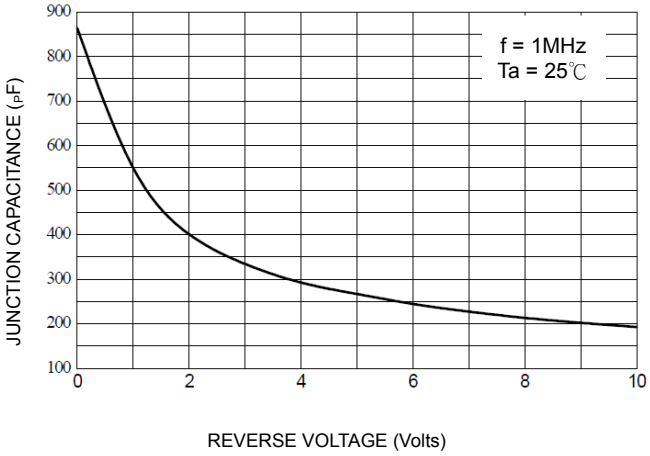
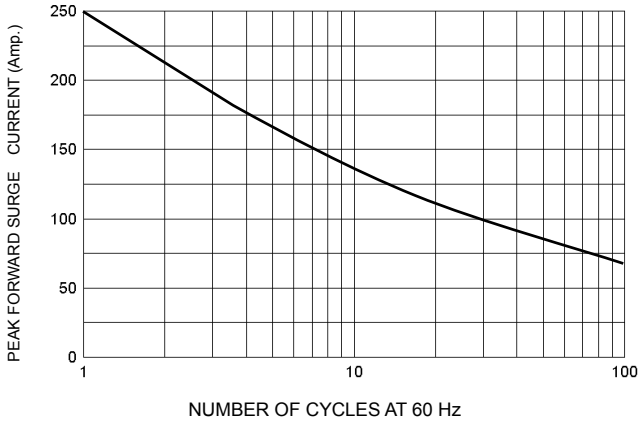


FIG-5 PEAK FORWARD SURGE CURRENT



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